

# NCE N-Channel Enhancement Mode Power MOSFET

# Description

The NCE0115K uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

### **General Features**

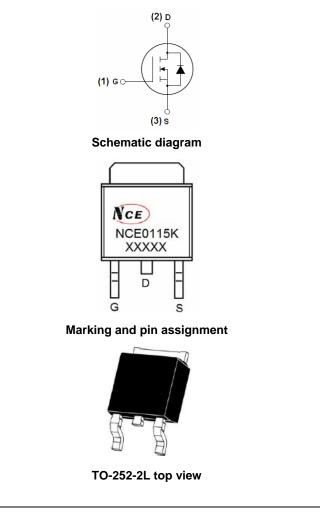
- $V_{DS} = 100V, I_D = 15A$   $R_{DS(ON)} < 100m\Omega @ V_{GS} = 10V$  (Typ:80m $\Omega$ )  $R_{DS(ON)} < 110m\Omega @ V_{GS} = 4.5V$  (Typ:85m $\Omega$ )
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

# Application

- Power switching application
- Hard switched and high frequency circuits

100% UIS TESTED!

100% ΔVds TESTED!



#### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0115K	NCE0115K	TO-252-2L	-	-	-

#### Absolute Maximum Ratings (T<sub>c</sub>=25<sup>°</sup>Cunless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	VDS	100	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous	I <sub>D</sub>	15	A	
Drain Current-Continuous(T <sub>C</sub> =100°C)	I <sub>D</sub> (100℃)	10.6	A	
Pulsed Drain Current	I <sub>DM</sub>	60	A	
Maximum Power Dissipation	PD	50	W	
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	200	mJ	
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 175	°C	



## **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	R <sub>θJC</sub>	3	°C/W
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## **Electrical Characteristics (Tc=25**°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	100	110	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20V, $V_{DS}$ =0V	-	-	±100	nA
On Characteristics (Note 3)	····					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.1	1.5	2.0	V
Drain Course On Chata Desintance	D	V <sub>GS</sub> =10V, I <sub>D</sub> =10A	-	80	100	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	$V_{GS}$ =4.5V, I <sub>D</sub> =10A	-	85	110	
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =10A	-	10	-	S
Dynamic Characteristics (Note4)	<b>i</b>					
Input Capacitance	C <sub>lss</sub>		-	830	-	PF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =50V, $V_{GS}$ =0V,	-	44.2	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	30.1	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	15	-	nS
Turn-on Rise Time	tr	$V_{DD}$ =50V, RL=6. 4 $\Omega$	-	5	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =3 $\Omega$	-	25	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	7	-	nS
Total Gate Charge	Qg		-	22.3		nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =50V,I <sub>D</sub> =10A, V <sub>GS</sub> =10V	-	2.87	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	6.14	-	nC
Drain-Source Diode Characteristics			•		•	
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =15A	-	-	1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	15	Α
				1		

Notes:

**1.** Repetitive Rating: Pulse width limited by maximum junction temperature.

**2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.

**3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

4. Guaranteed by design, not subject to production

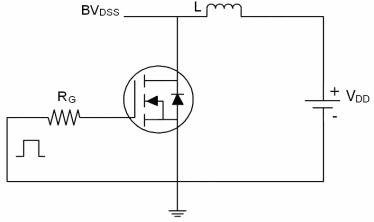
5. EAS condition : Tj=25  $^\circ\!\mathrm{C}$  ,V\_{DD}=50V,V\_G=10V,L=0.5mH,Rg=25\Omega

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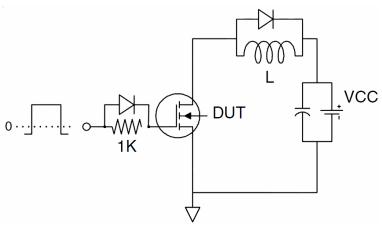


# Test Circuit

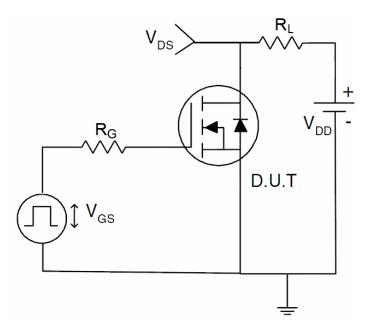
1) E<sub>AS</sub> test Circuit



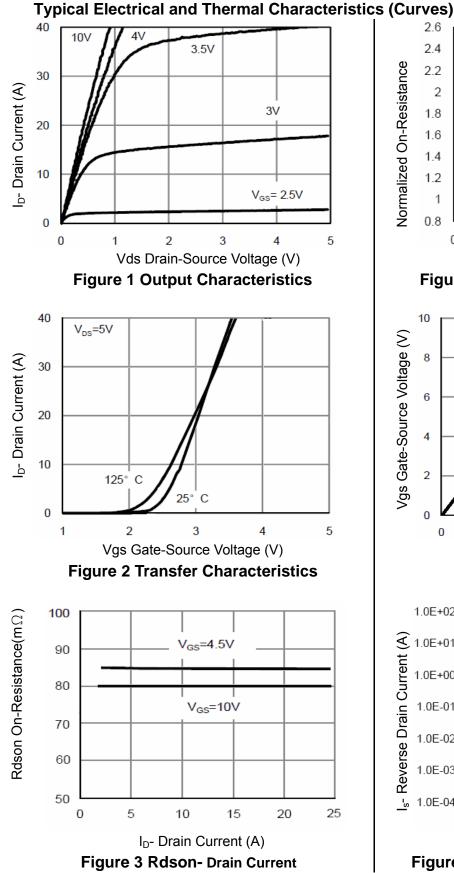
## 2) Gate charge test Circuit

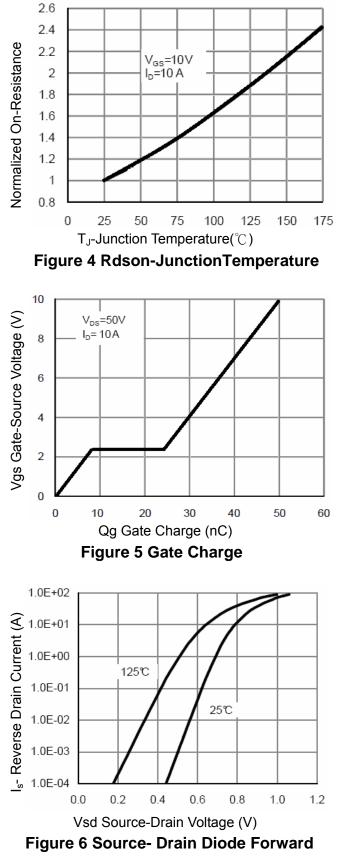


3) Switch Time Test Circuit





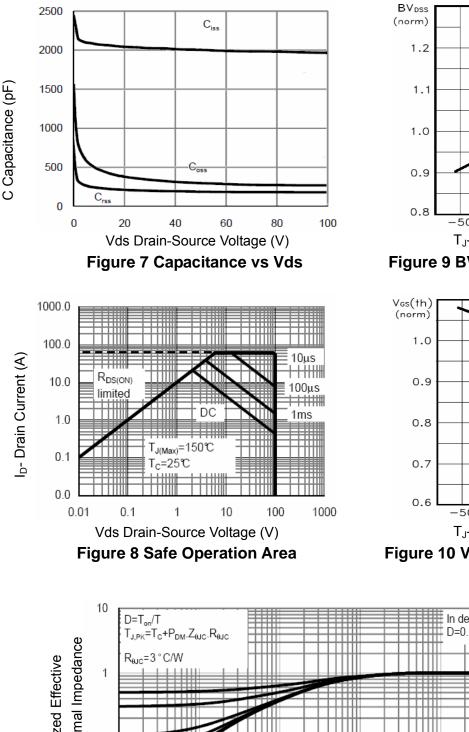






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# NCE0115K



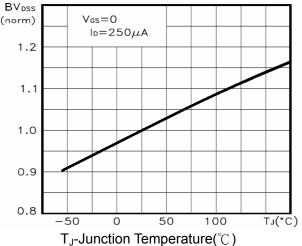


Figure 9 BV<sub>DSS</sub> vs Junction Temperature

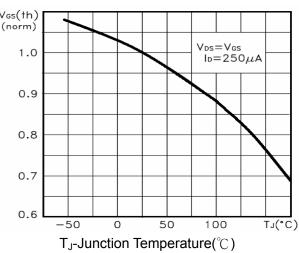
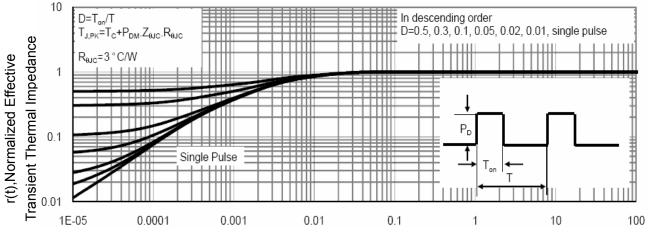


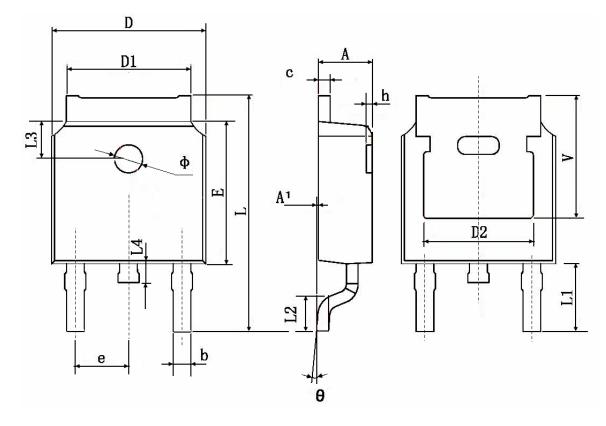
Figure 10 V<sub>GS(th)</sub> vs Junction Temperature



Square Wave Pluse Duration(sec) Figure 11 Normalized Maximum Transient Thermal Impedance



# **TO-252 Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.83	0 TYP.	TYP.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900			14 TYP.	
L2	1.400	1.700	0.055	0.067	
L3	1.600			063 TYP.	
L4	0.600	1.000	0.024	0.039	
Φ	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350	) TYP.	0.211 TYP.		



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